

Features

- Low VCE(sat) with Trench technology
- Low switching losses especially Eoff
- VCE(sat) with positive temperature coefficient
- High short circuit capability(10us)
- Including ultra fast & soft recovery anti-parallel FWD
- Low inductance package
- Maximum junction temperature 175 °C
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant (Note1)("P" Suffix Designates RoHS Compliant. See Ordering Information)

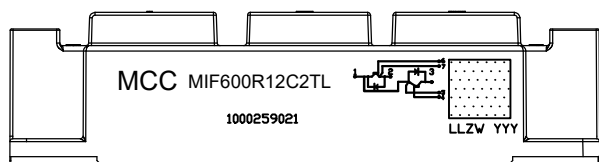
Applications

- Motion/Sevo Control
- High Frequency Switching Application
- UPS(Uninterruptible Power Supplies)
- Welding Machine

Parameter	Symbol	Rating	Unit
Collector-Emitter Voltage@ $V_{GE}=0V, I_C=1mA, T_{vj}=25^{\circ}C$	V_{CES}	1200	V
Continuous Collector Current @ $T_C=100^{\circ}C$	I_C	600	A
Repetitive Peak Collector Current @ $t_p=1ms$	I_{CRM}	1200	A
Gate-Emitter Voltage@ $T_{vj}=25^{\circ}C$	V_{GE}	± 20	V
Total Power Dissipation (IGBT-Inverter)	$T_C=25^{\circ}C$	P_{tot}	W
	$T_{vjmax}=175^{\circ}C$		

Note:

1. High Temperature Solder Exemptions Applied, see EU Directive Annex 7a.



Marking Code Contents:

Logo: MCC

Product Number:MIF600R12C2TL

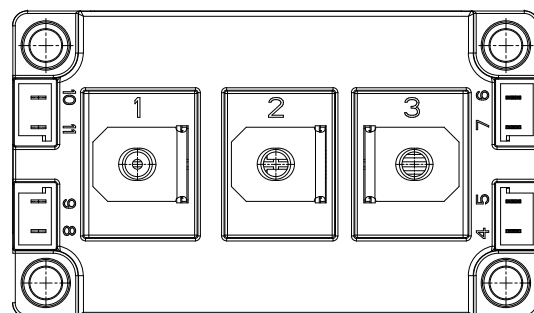
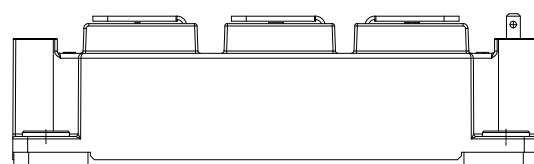
Trace Code: 10 Digits

Circuit Diagram

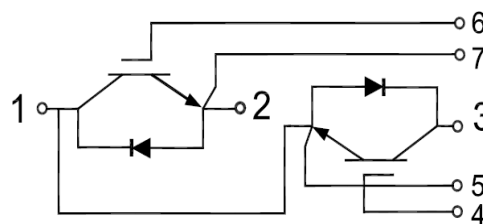
2D Code format: Data Matrix

IGBT Modules 1200V 600A

C2



Circuit Diagram



Electrical Characteristics of IGBT @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Gate-emitter Threshold Voltage	$V_{GE(th)}$	$I_C=12mA, V_{CE}=V_{GE}, T_{vj}=25^{\circ}C$	5.2	5.8	6.4	V
Collector-Emitter Cut-off Current	I_{CES}	$V_{CE}=1200V, V_{GE}=0V, T_{vj}=25^{\circ}C$			1.0	mA
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=600A, V_{GE}=15V, T_{vj}=25^{\circ}C$		1.95	2.5	V
		$I_C=600A, V_{GE}=15V, T_{vj}=125^{\circ}C$		2.25		
		$I_C=400A, V_{GE}=15V, T_{vj}=150^{\circ}C$		2.35		
Gate Charge	Q_G			4.4		μC
Internal Gate Resistance	R_{gint}			1.25		Ω
Input Capacitance	C_{ies}	$V_{CE}=25V, V_{GE}=0V, f=1MHz, T_{vj}=25^{\circ}C$		101.5		nF
Reverse Transfer Capacitance	C_{res}			0.8		
Gate-Emitter leakage current	I_{GES}	$V_{CE}=0V, V_{GE}=20V, T_{vj}=25^{\circ}C$			400	nA
Turn-On Delay Time	$td_{(on)}$	$V_{CE}=600V, I_C=600A, V_{GE}=\pm 15V, R_G=1.1\Omega, T_{vj}=25^{\circ}C$		135		ns
Rise Time	t_r			84		
Turn-Off Delay Time	$td_{(off)}$			350		
Fall Time	t_f			174		
Turn-On Energy	E_{on}			90		mJ
Turn-Off Energy	E_{off}			46.6		
Turn-On Delay Time	$td_{(on)}$	$V_{CE}=600V, I_C=600A, V_{GE}=\pm 15V, R_G=1.1\Omega, T_{vj}=150^{\circ}C$		153		ns
Rise Time	t_r			102		
Turn-Off Delay Time	$td_{(off)}$			407		
Fall Time	t_f			278		
Turn-On Energy	E_{on}			134.5		mJ
Turn-Off Energy	E_{off}			60.5		
SC Data	I_{sc}	$t_p \leq 10\mu s, V_{GE}=15V, T_{vj}=150^{\circ}C, V_{cc}=900V, V_{CEM} \leq 1200V$		2400		A

Electrical Characteristics of DIODE @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	$T_{vj}=25^{\circ}\text{C}$	1200	V
Continuous DC Forward Current	I_F		600	A
Repetitive Peak Forward Current	I_{FRM}	$t_p=1\text{ms}$	1200	A
I2t-value	I^2t	$V_R=0\text{V}, t_p=10\text{ms}, T_{vj}=125^{\circ}\text{C}$	35000	A^2s
		$V_R=0\text{V}, t_p=10\text{ms}, T_{vj}=150^{\circ}\text{C}$	32000	

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Forward Voltage	V_F	$I_F=600\text{A}, T_{vj}=25^{\circ}\text{C}$		1.55	2.1	V
		$I_F=600\text{A}, T_{vj}=125^{\circ}\text{C}$		1.46		
		$I_F=600\text{A}, T_{vj}=150^{\circ}\text{C}$		1.41		
Recovered Charge	Q_{rr}	$I_F=600\text{A}$ $V_R=600\text{V}$		68.9		μC
Peak Reverse Recovery Current	I_{rr}	$-diF/dt = 5700\text{A/us}$		296		A
Reverse Recovery Energy	E_{rec}	$T_{vj}=25^{\circ}\text{C}$		18.5		mJ
Recovered Charge	Q_{rr}	$I_F=600\text{A}$ $V_R=600\text{V}$		136.1		μC
Peak Reverse Recovery Current	I_{rr}	$-diF/dt = 5700\text{A/us}$		343		A
Reverse Recovery Energy	E_{rec}	$T_{vj}=150^{\circ}\text{C}$		39.8		mJ

Module Characteristics

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Isolation Voltage	V_{isol}	$t=1\text{min}, f=50\text{Hz}$	2500			V
Maximum Junction Temperature	T_{jmax}				175	$^{\circ}\text{C}$
Operating Junction Temperature	$T_{vj\text{ op}}$		-40		150	$^{\circ}\text{C}$
Storage Temperature	T_{stg}		-40		125	$^{\circ}\text{C}$
Thermal Resistance Junction to Case	$R_{\theta JC}$	per IGBT			0.043	K/W
		per Diode			0.075	
Thermal Resistance Case-to Sink	$R_{\theta CS}$	Conductive grease applied		0.035		K/W
Comparative Tracking Index	CTI		400			
Module Electrodes Torque	M_t	Recommended(M6)	3.0		5.0	N.m
Module to Sink Torque	M_s	Recommended(M6)	3.0		5.0	N.m
Weight of Module	G			315		g

Curve Characteristics

Fig1.IGBT Output Characteristics

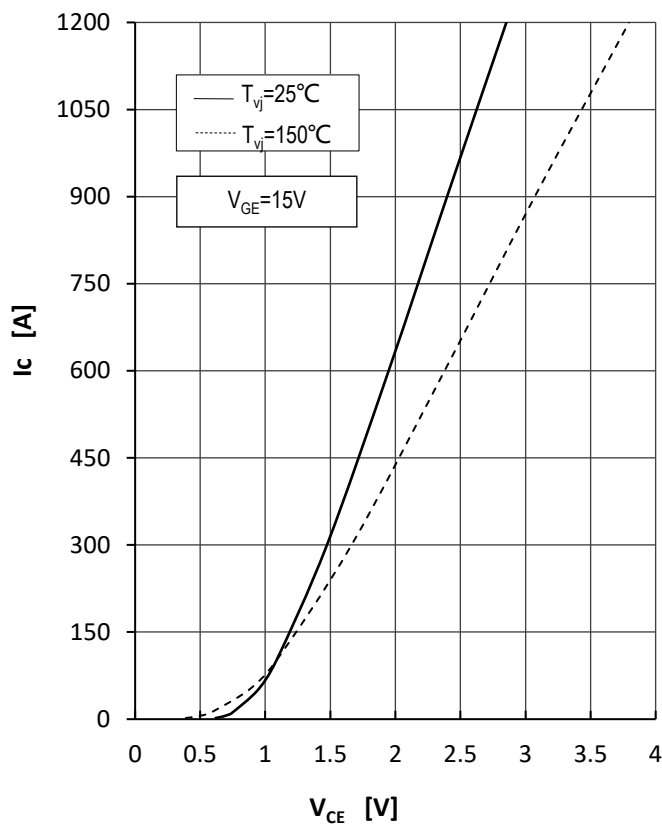


Fig2.IGBT Transfer Characteristics

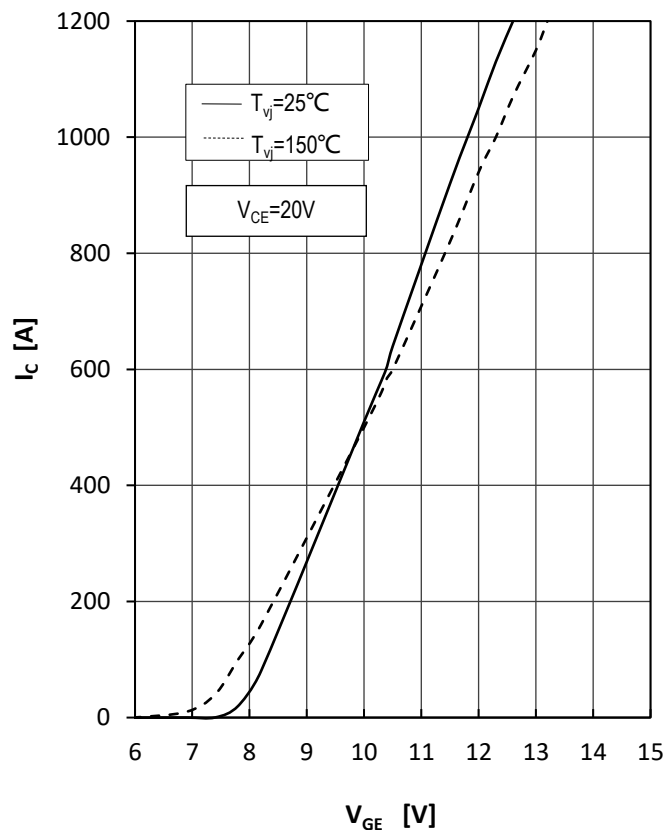


Fig3.IGBT Switching Loss vs.Ic

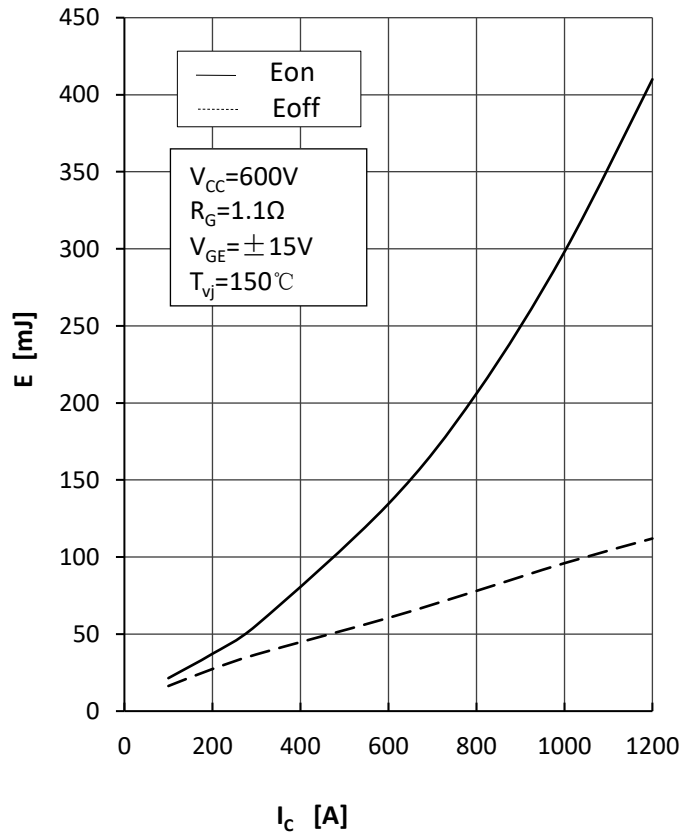
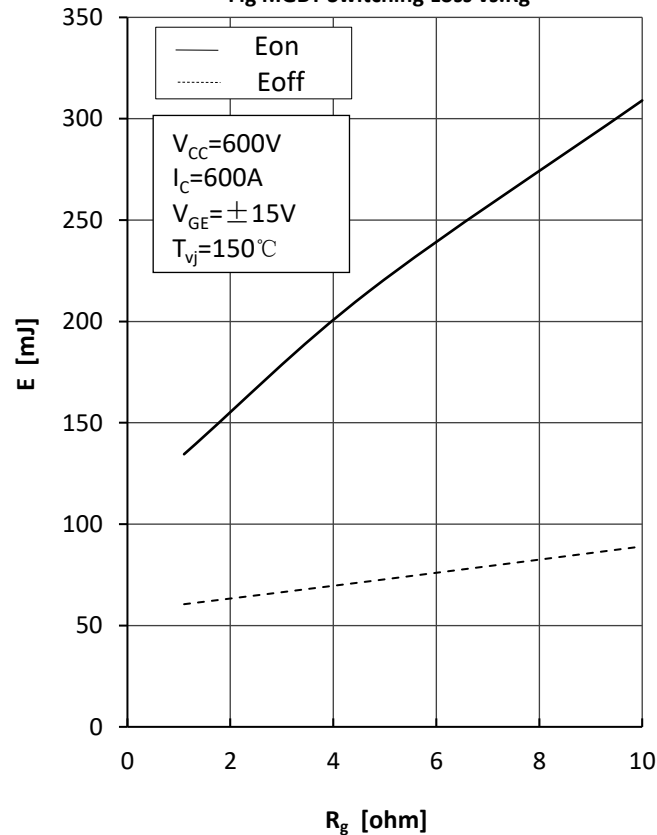


Fig4.IGBT Switching Loss vs.Rg



Curve Characteristics

Fig5. RBSOA

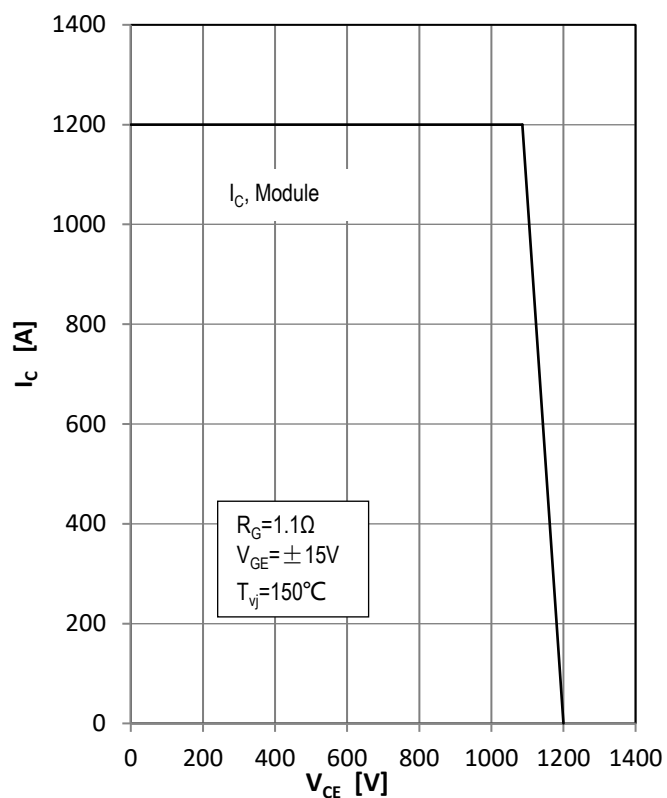


Fig 6. IGBT Transient Thermal Impedance

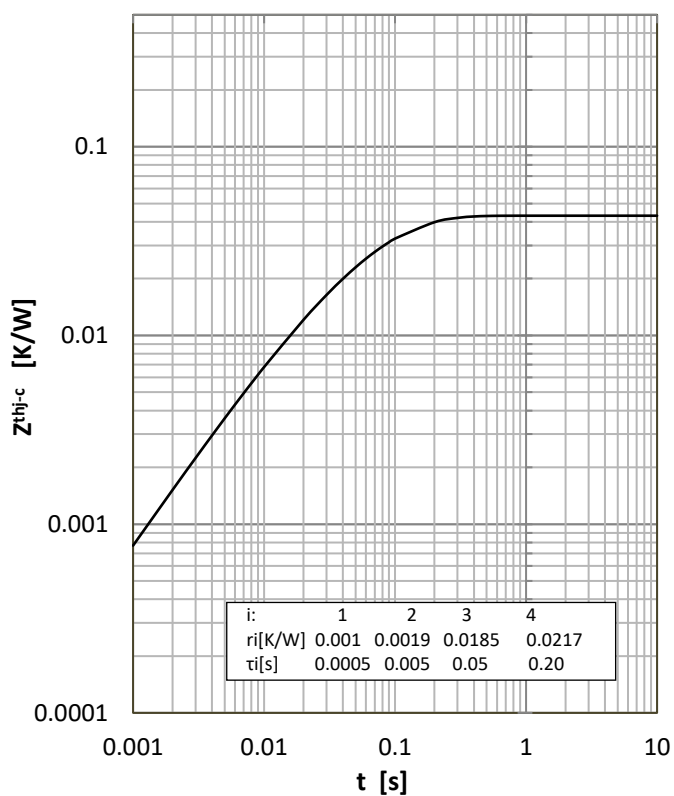


Fig7.Diode Foward Characteristics

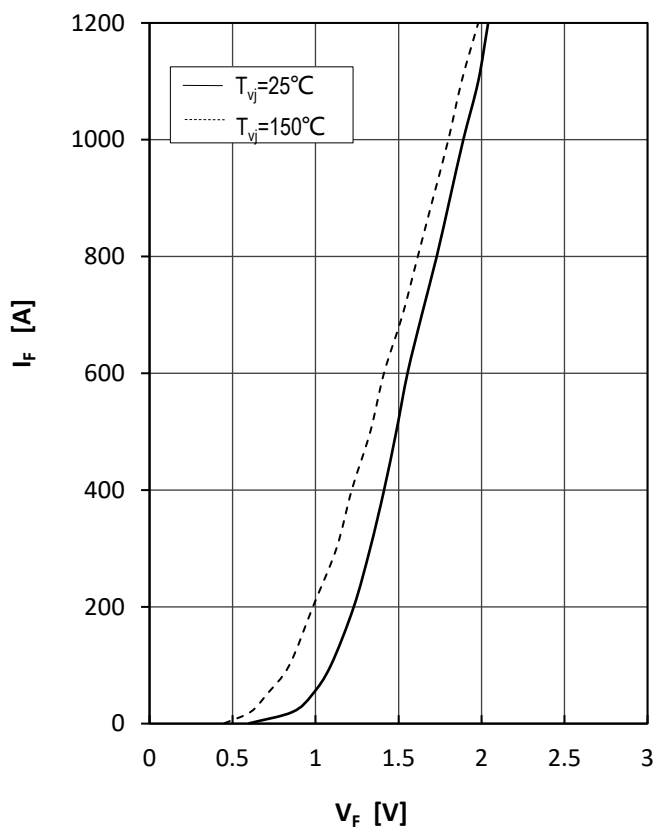
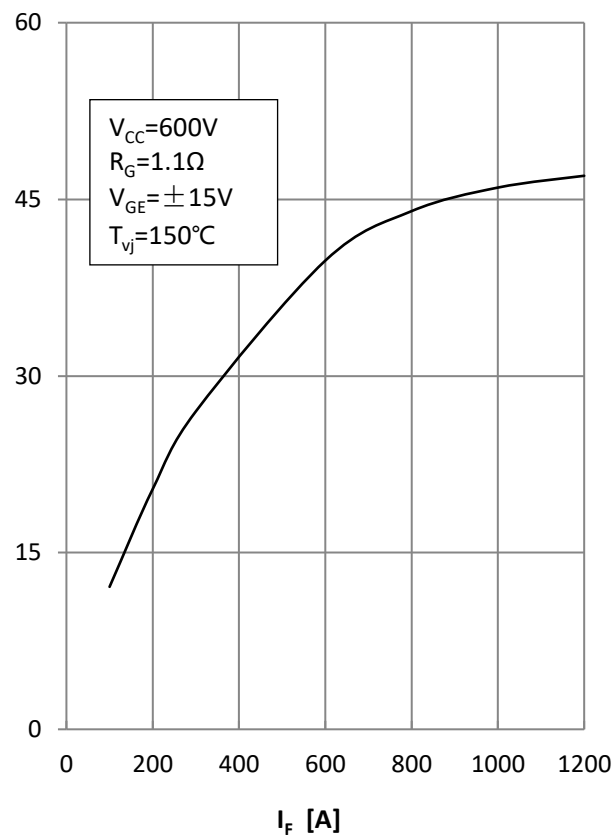


Fig8.Diode Switching Loss(E_{rec}) vs. I_F



Curve Characteristics

Fig9.Diode Switching Loss(E_{rec}) vs. R_g

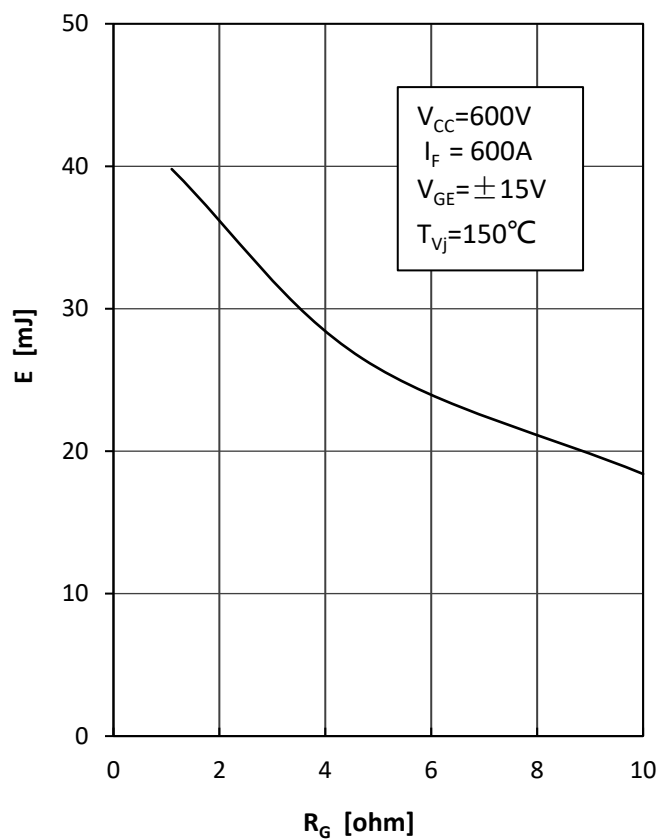
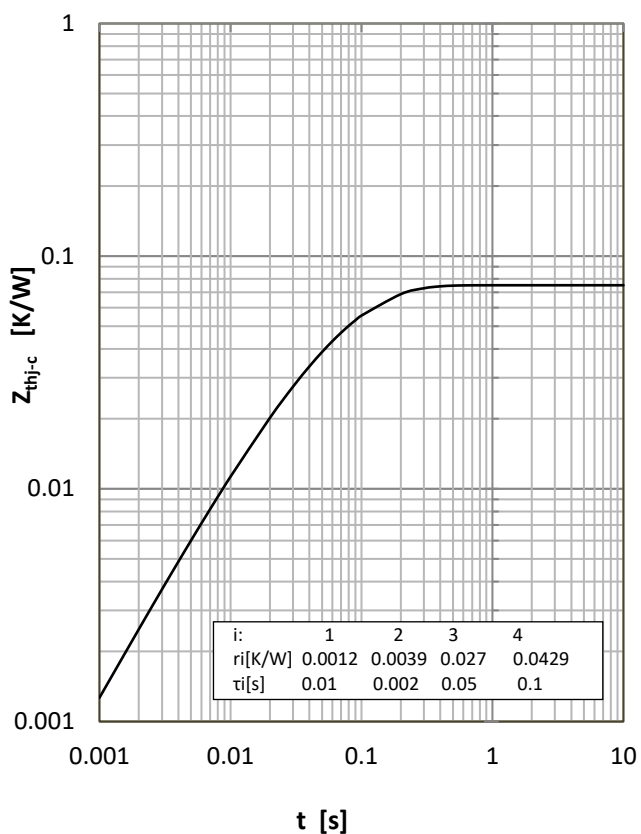


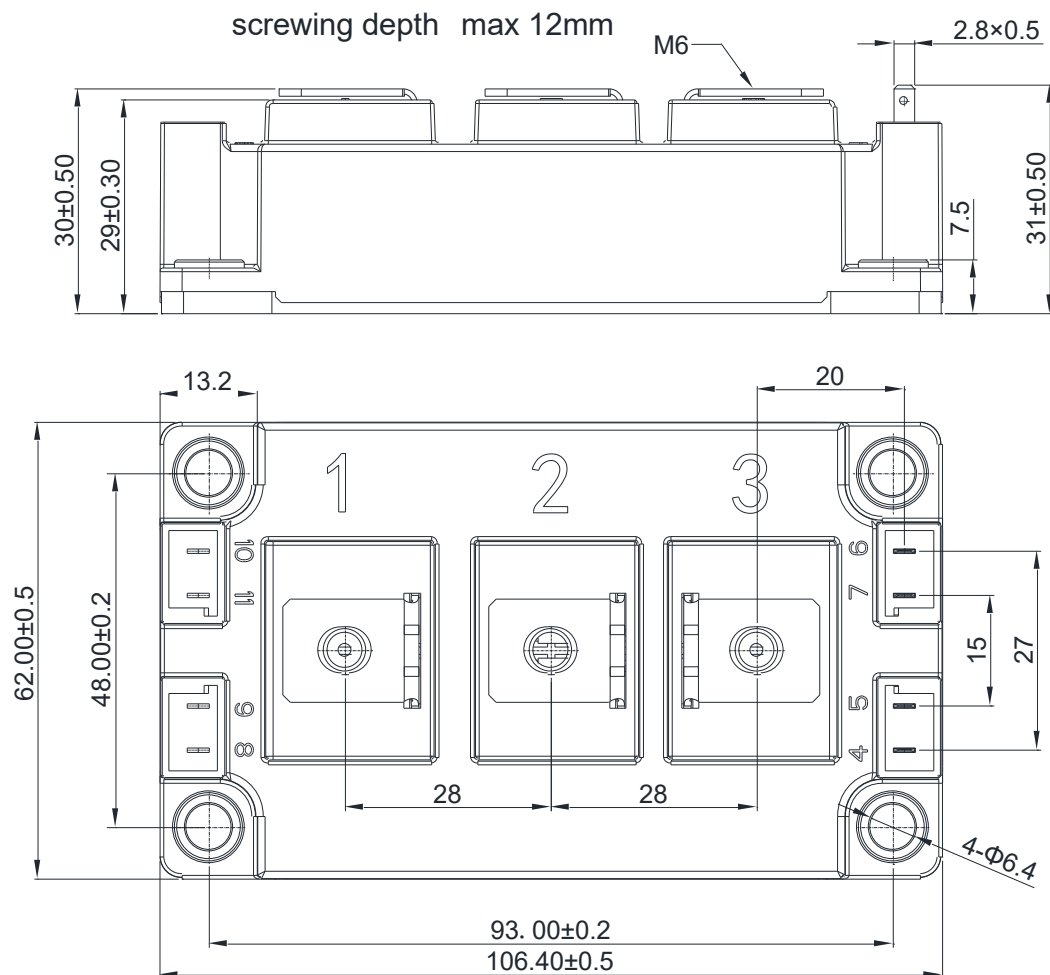
Fig10.Diode Transient Thermal Impedance



Package Dimensions

C2

Dimensions in Millimeters



Ordering Information

Device	Packing
Part Number-BP	Bulk: 6pcs/Box ; 30pcs/Ctn

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